## NSN 5961-00-924-9612

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-00-924-9612 **Inclosure Material:** Metal **Overall Length:** 0.468 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.437 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 breakdown voltage, collector-to-base, emitter open and 100.0 breakdown voltage, collector-to-emitter, base open and 10.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** Between 1.00 amperes source cutoff current and 2.00 amperes source cutoff current **Power Rating Per Characteristic:** 40.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius case **Special Features:** Junction pattern arrangement: pnp **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 tab, solder lug **Specification Data:** 80131-release4663 professional/industrial association specification Shelf Life: N/a **Unit Of Measure:** 

No

Demilitarization:

## **NSN 5961-00-924-9612** Transistor - Page 2 of 2



Fiig:

A110a0